

PIP201-12M-3 DC-to-DC converter powertrain Rev. 03 – 19 November 2003

Product data

1. Description

The PIP201-12M is designed for use as the power output stage of a synchronous buck DC-to-DC converter. It contains a MOSFET control IC and two power MOSFET transistors. By combining the power MOSFETs and the driver circuit into a single component, stray inductances are virtually eliminated, resulting in higher switching frequency, lower switching losses and a compact, efficient design.

2. Features

- Input conversion range from 3.3 V to 12 V
- Output voltages from 0.8 V to 5 V
- Capable of up to 20 A continuous output current
- Operating frequency up to 1 MHz
- Peak system efficiency >90% at 500 kHz
- Low-profile, surface mount package $(10 \times 10 \times 0.85 \text{ mm})$
- Compatible with any single or multi-phase PWM controller.

3. Applications

- High-current DC-to-DC point-of-load converters
- Small form-factor Voltage Regulator Modules
- Microprocessor and memory voltage regulators.

4. Ordering information

Table 1: Ordering information

Type number	Package					
	Name	Description	Version			
PIP201-12M-3	HVQFN68 (MLF68)	plastic thermal enhanced very thin quad flat package; no leads; 68 terminals; body $10 \times 10 \times 0.85$ mm	SOT687-1			



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5. Block diagram



6. Pinning information

6.1 Pinning



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6.2 Pin description

Table 2:	Pin description			
Symbol	Pin		I/O	Description
V _{DDO}	1 to 8, 60, 61, 68	[1][4]	-	output stage supply voltage
V _{SSC}	9, 15, 22 to 24	[2][4]	-	control circuit supply ground
Vo	10, 26, 27, 45 to 59, 62 to 67	[3][4]	0	output
СВ	11, 12		I/O	bootstrap capacitor connection
V _{DDC}	13, 14		-	control circuit supply voltage
VI	16, 17		I	pulse width modulated input
V _{SSO}	28 to 44		-	output stage supply ground
n.c.	18 to 21, 25	[5]	-	no internal connection

[1] All pins connected to PAD1

[2] All pins connected to PAD2

[3] All pins connected to PAD3.

[4] PAD1, PAD2 and PAD3 are electrical connections and must be soldered to the printed circuit board.

[5] All n.c. pins should be connected to V_{SSC} .

7. Functional description

7.1 Basic functionality



In order to understand the functions performed by the PIP201-12M, consider the requirements of a synchronous DC-to-DC converter output stage, driven from a PWM controller (Figure 3).

When the input voltage is HIGH, the upper MOSFET must be on and the lower MOSFET must be off. Current flows from the supply (V_{DDO}), through the upper MOSFET and the inductor (L_{out}), to the output.

When the input voltage is LOW and current is flowing in the inductor, the upper MOSFET must be off and the lower MOSFET must be on. Current flows from the power ground (V_{SSO}), through the lower MOSFET and the inductor (L_{out}), to the output.

Finally, when switching between states, both MOSFETs must not be on at the same time.

7.2 MOSFET driver function



The input, output and gate drive waveforms are shown in Figure 4. When the input voltage goes HIGH, the gate drive to the lower MOSFET immediately goes LOW. This causes the output current to flow through the source-drain diode of the lower MOSFET. This causes output voltage to fall from zero to approximately –0.7 V.

After a delay, if the input voltage is still HIGH, the gate drive to the upper MOSFET goes HIGH. This causes the output voltage to rise to the output stage supply voltage, $V_{\text{DDO.}}$

When the input voltage goes LOW, the gate drive to the upper MOSFET immediately goes LOW. The output voltage falls from V_{DDO} , until it is clamped by the source-drain diode of the synchronous FET at approximately -0.7 V.

After a delay, if the input voltage is still LOW, the gate drive to the lower MOSFET goes HIGH. The lower MOSFET turns on, and the output voltage rises from -0.7 V to zero.

7.3 Bootstrap diode

A bootstrap diode is integrated into the design of the PIP201-12M between V_{DDC} and CB.

7.4 3-state function

If the input from the PWM controller becomes high impedance (3-state) for longer than $t_{d(3-state)}$, then both MOSFETs are turned off and the V_I input is driven to 2.5 V by an internal 2 x 10 k Ω resistor voltage divider between an internal 5 V reference and ground. Once the V_I input is outside the 3-state window for longer than $t_{d(3-state)}$ normal operation will commence.

8. Limiting values

Table 3: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DDC}	control circuit supply voltage			-0.5	15	V
V _{DDO}	output stage supply voltage			-0.5	25	V
VI	input voltage			-0.5	5.25	V
Vo	output voltage			-0.5	$V_{DDO} + 0.5$	V
V _{CB}	bootstrap voltage			-0.5	V _O + 15	V
I _{O(AV)}	average output current	V_{DDC} = 12 V; $T_{pcb} \le$ 112 °C; f _i = 500 kHz; Figure 5		-	20	А
I _{ORM}	repetitive peak output current	V_{DDC} = 12 V; $t_p \le$ 10 μ s	[1]	-	200	А
P _{tot}	total power dissipation	T _{pcb} = 25 °C	[2]	-	25	W
		T _{pcb} = 90 °C	[2]	-	12	W
T _{stg}	storage temperature			-55	+150	°C
Tj	junction temperature			-55	+150	°C

[1] Pulse width and repetition rate limited by maximum value of T_i.

[2] Assumes a thermal resistance from junction to printed-circuit board of 5 K/W.



9. Thermal characteristics

Table 4:	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-pcb)}	thermal resistance from junction to printed-circuit board		-	4	5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	device mounted on FR4 printed-circuit board; copper area around device 25×25 mm				
		no thermal vias	-	25	-	K/W
		with thermal vias	-	20	-	K/W
		with thermal vias and forced air cooling; airflow = 0.8 ms ⁻¹ (150 LFM)	-	15	-	K/W
R _{th(j-c)}	thermal resistance from junction to case	measured on upper surface of package	-	11	-	K/W

10. Characteristics

Table 5: Characteristics

 V_{DDC} = 12 V; T_i = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static char	acteristics						
V _{DDC}	control circuit supply voltage	$25 \ ^{\circ}C \le T_{j} \ \le 150 \ ^{\circ}C$		7	12	14	V
V _{IH}	HIGH-level input voltage	$25 \ ^\circ C \leq T_j \ \leq 150 \ ^\circ C$	[1]	3.0	3.45	3.9	V
V _{IL}	LOW-level input voltage	$25 \ ^\circ C \leq T_j \ \leq 150 \ ^\circ C$	[1]	1	1.45	1.9	V
ILI	input leakage current	$0 \ V \leq V_I \leq 5 \ V$		-	0.3	1.2	mA
IDDC	control circuit supply current	f _i = 0 Hz		-	1.5	3	mA
		f _i = 500 kHz; Figure 10		-	45	60	mA
P _{tot}	total power dissipation	$\begin{split} V_{DDO} &= 12 \text{ V; } I_{O(AV)} = 12.5 \text{ A;} \\ f_i &= 500 \text{ kHz; } V_O = 1.6 \text{ V;} \\ T_{pcb} &= 90 ^{\circ}\text{C; } \text{Figure 6.} \end{split}$		-	2.7	-	W
Dynamic c	haracteristics						
t _{d(on)(IH-OH)}	turn-on delay time input HIGH to output HIGH	$V_{DDO} = 12 \text{ V}; \text{ I}_{O(AV)} = 12.5 \text{ A}$		-	77	85	ns
$t_{d(off)(\text{IL-OL})}$	turn-off delay time input LOW to output LOW			-	30	45	ns
t _{o(r)}	output rise time			-	18	25	ns
t _{o(f)}	output fall time			-	12	20	ns
t _{d(3-state)}	3-state delay time			-	140	-	ns

[1] If the input voltage remains between V_{IH} and V_{IL} (2.5 V typ) for longer than $t_{d(3-state)}$, then both MOSFETs are turned off.

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11. Application information



11.1 Typical application

Fig 11. Typical application circuit using the PIP201-12M in a four-phase converter

A typical four-phase buck converter is shown in Figure 11. This system uses four PIP201-12M devices to deliver a continuous output current of 50 A at an operating frequency of 500 kHz.

Remark: An external bootstrap diode is not required as one is already integrated into the design of the PIP201-12M between V_{DDC} and CB.

The typical dissipation in each PIP201-12M as a function of output current, is given in Figure 6. At 500 KHz and 12.5 A output current, the dissipation in each PIP201-12M is 2.7 W. The typical thermal resistance from junction to ambient is given in Table 4. With thermal vias and forced air cooling, the thermal resistance of each PIP201-12M from junction to ambient is15 K/W. Assuming a maximum ambient temperature of 55 °C, the maximum junction temperature ($T_{i(max)}$) is given by:

$$T_{j(max)} = P_{tot} \times R_{th(j-a)} + T_{amb} = 2.7 \times 15 + 55 = 95.5^{\circ}C$$
(1)

The thermal resistance between the junction and the printed-circuit board is 5 K/W. Therefore, the maximum printed-circuit board temperature $(T_{pcb(max)})$ is given by:

$$T_{pcb(max)} = T_{j(max)} - P_{tot} \times R_{th(j-pcb)} = 95.5 - 2.7 \times 5 = 82^{\circ}C$$
(2)

11.2 Advantages of an integrated driver

One problem in the design of low-voltage, high-current DC-to-DC converters using discrete components, is stray inductance between the various circuit elements.

Stray inductance in the gate drive circuit increases the switching times of the MOSFETs and causes high-frequency oscillation of the gate voltage.

Stray inductance in the high-current loop between V_{DDO} and V_{SSO} causes switching losses and electromagnetic interference. In discrete designs, high-frequency electric and magnetic fields radiate from PCB tracks and couple into adjacent circuits.

By integrating the power MOSFETs and their drive circuits into a single package, stray inductance is virtually eliminated, resulting in a compact, efficient design.

In discrete designs, the delays in the MOSFET drivers must be long enough to ensure no cross-conduction even when using the slowest MOSFETs. Use of an integrated driver allows the propagation delays in the MOSFET drivers to be precisely matched to the MOSFETs. This minimizes switching losses and eliminates cross-conduction whilst allowing the circuit to operate at a higher frequency.

11.3 External connection of power and signal lines

A major benefit of the PIP201-12M module is the ability to switch the internal power MOSFETs faster than a DC-to-DC converter built from discrete components. This reduces switching losses and increases system efficiency but it also results in higher transient voltages on the device supply lines (V_{DDO} and V_{SSO}). This is due to the high rate of change of current (dI/dt) through the combined parasitic inductance of the pcb tracks and the decoupling capacitors.

To minimize the amplitude of these transients, decoupling capacitors must be placed between V_{DDO} and V_{SSO} , as close as possible to the device pins. Low inductance, chip ceramic capacitors are recommended.

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To protect the control circuit from the transient voltages, the following precautions must be taken. Refer to Figure 12.

- The output stage ground (V_{SSO}) must be connected to the decoupling capacitor (C_{in}) before joining the ground plane. Otherwise, the switching noise on V_{SSO} will couple into the control circuit ground (V_{SSC}).
- 2. The control circuit supply must be filtered using a resistor-capacitor (RC) filter. The values shown in Figure 12 are suitable for most applications.
- 3. It is essential that the V_{SSC} (signal ground) connection at the device is not connected in the current return path between the V_{SSO} (power ground) connection at the device and the V_{DDO} input capacitor.
- 4. It is also essential that the input to the V_{DDC} (logic power) filter is not connected in the current path between the V_{DDO} (conversion power) connection at the device.

11.4 Switching frequency

A high operating frequency reduces the size and number of capacitors needed to filter the output current, and also reduces the size of the output inductors. The disadvantage is higher dissipation due to switching and MOSFET driver losses. For example, doubling the operating frequency of the circuit in Figure 11 from 500 kHz to 1 MHz would increase the power dissipation in each PIP201-12M from 2.7 W to 4.5 W, at an output current of 12.5 A in each PIP201-12M.

The maximum switching frequency is limited by thermal considerations, the dissipation in the PIP201-12M device(s) and the thermal resistance from junction to ambient.

11.5 Thermal design

The PIP201-12M has three pads on its underside. These are designated PAD1, PAD2 and PAD3 (Figure 2). PAD1 is connected to V_{DDO} , PAD2 is connected to V_{SSC} and PAD3 is connected to V_O . In addition to providing low inductance electrical connections, these pads conduct heat away efficiently from the MOSFETs and control IC to the printed-circuit board. The thermal resistance from junction to

printed-circuit board is approximately 5 K/W. In order to take full advantage of the low thermal resistance of this package, the printed-circuit board must be designed so that heat is conducted away efficiently from the package. This can be achieved by maximizing the area of copper around each pad, and by incorporating thermal vias to conduct the heat to inner and/or bottom layers of the printed-circuit board.

An example of a thermal via pattern is shown in Figure 13. In a typical application, with no forced air cooling, the use of thermal vias typically reduces the thermal resistance from 25 K/W to 20 K/W. The additional use of a small fan can reduce this further to approximately 15 K/W.



All holes 0.5 mm diameter with 1 mm spacing.

Fig 13. Printed-circuit board thermal via pattern.

The thermal resistance of a particular design can be measured by passing a known current through the source-drain diode of the lower MOSFET. The direction of current flow is into V_{SSO} and out of V_O . The volt drop between V_{SSO} and V_O is then measured and used to calculate the power dissipation in the PIP201-12M. The case temperature of the PIP201-12M can be measured using an infra-red thermometer. The thermal resistance can then be calculated using the following equation:

$$R_{th(j-pcb)} = \frac{T_{case} - T_{amb}}{I \times V_F} (K/W)$$
(3)

where T_{case} is the measured case temperature (°C), T_{amb} is the ambient temperature (°C), I is the MOSFET current (A), and V_F is the voltage drop between V_{SSO} and V_{DDO} (V).

Where more than one phase is used, for example the circuit of Figure 11, the thermal resistance of each PIP201-12M should be measured with current flowing in all phases.

12. Test information

Figure 14 shows the test circuit used to measure power loss in the PIP201-12M. The output voltage is measured using an averaging circuit. This eliminates losses in the output inductor and the PCB tracks. The calculated power loss, using this method,

includes the losses in the Equivalent Series Resistance (ESR) of the input filter capacitors. This must be subtracted from the total loss to give the net loss in the PIP201-12M.



13. Marking



14. Package outline



HVQFN68: plastic thermal enhanced very thin quad flat package; no leads; 68 terminals; body 10 x 10 x 0.85 mm

SOT687-1

Fig 17. SOT687-1.

15. Soldering

15.1 Introduction to soldering MLF packages

The MicroLeadFrame package (MLF) is a near Chip Scale Package (CSP) with a copper leadframe. It is a leadless package, where electrical contact to the printed circuit board is made through metal pads on the underside of the package. In addition to the small pads around the periphery of the package, there are large pads on the underside that provide low thermal resistance, low electrical resistance, low inductance connections between the power components inside the MLF package and the printed-circuit board. It is this feature of the MLF package that makes it ideally suited for VRM applications.

Electrical connection between the package and the printed circuit board is made by printing solder paste on the printed circuit board, placing the component and reflowing the solder in a convection or infra-red oven. The solder reflow process is shown in Figure 18 and the typical temperature profile is shown in Figure 19. To ensure good solder joints, the peak temperature T_p should not exceed 220 °C for thin packages such as MLF, and the time above liquidus temperature should be less than 1.25 minutes. The maximum temperature can be increased for lead free solder. The ramp rate during preheat should not exceed 3 K/s. Nitrogen purge is recommended during reflow.



15.2 Rework guidelines

Since the solder joints are largely inaccessible, only the side fillets can be touched up. If there are defects underneath the package, then the whole package has to be removed.

The first step in component removal is to reflow the solder joints. It is recommended that the board is heated from the underside using a convective heater whilst hot air or gas is directed at the upper surface of the component. Nozzles should be used to direct the hot air or gas to minimize heating of adjacent components. Excessive airflow should be avoided since this may cause the package to skew. An airflow velocity of 15 to 20 liters per minute is usually adequate.

Once the solder joints have reflowed, the component should be lifted off the board using a vacuum pen.

The next step is to clean the solder pads using solder braid and a blade-style soldering tool. Finally, the pads should be cleaned with a solvent. The solvent is usually specific to the type of solder paste used in the original assembly and the paste manufacturers recommendations should be followed.

16. Mounting

16.1 PCB design guidelines

The terminals on the underside of the package are rectangular in shape with a rounded edge on the inside. Electrical connection between the package and the printed-circuit board is made by printing solder paste onto the PCB footprint followed by component placement and reflow soldering. The PCB footprint shown in Figure 20 is designed to form reliable solder joints.

The use of solder resist between each solder land is recommended. PCB tracks should not be routed through the corner areas shown in Figure 20. This is because there is a small, exposed remnant of the leadframe in each corner of the package, left over from the cropping process.

Good surface flatness of the PCB lands is desirable to ensure accuracy of placement after soldering. Printed-circuit boards that are finished with a roller tin process tend to leave small lumps of tin in the corners of each land. Levelling with a hot air knife improves flatness. Alternatively, an electro-less silver or silver immersion process produces completely flat PCB lands.

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16.2 Solder paste printing

The process of printing the solder paste requires care because of the fine pitch and small size of the solder lands. A stencil thickness of 0.125 mm is recommended. The stencil apertures can be made the same size as the solder lands in Figure 20.

The type of solder paste recommended for MLF packages is "No clean", Type 3, due to the difficulty of cleaning flux residues from beneath the MLF package.

17. Revision history

Table	e 6: Revisi	on history	
Rev	Date	CPCN	Description
03	20031119	-	Product data (9397 750 11942)
			Modifications:
			• Table 5 "Characteristics" on page 6: Min, Typ and Max values changed for V_{IH} , V_{IL} and
			t _{d(3} -state).
02	20020718	-	Product data (9397 750 09833)
			Modifications:
			 Section 2 "Features" and Table 1 on page 1: updated.
			 Figure 1 on page 2 and Table 2 on page 3: n.c. pins added.
			 Section 7.4 "3-state function" on page 5: 3-state function clarified.
			 Section 8 "Limiting values" on page 5: V_{DDC} and V_{CB} increased to 14 V.
			• Section 9 "Thermal characteristics" on page 6: Thermal resistance with forced air cooling added. Thermal resistance from junction to case added.
			 Section 10 "Characteristics" on page 6: V_{DDC} added.
			 Figure 11 on page 9: Application diagram updated.
			 Section 11.3 "External connection of power and signal lines" on page 10: New section added.
			 Figure 15 on page 13: Marking details and Version number added.
			 Figure 17 on page 14: Package drawing updated.
			 Section 15 "Soldering" on page 15: Soldering section rewritten.
			 Section 16 "Mounting" on page 16: Mounting and Figure 20 updated.
01	20020124	-	Preliminary data (9397 750 09032)

18. Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2][3]}	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

19. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Contact information

For additional information, please visit http://www.semiconductors.philips.com. For sales office addresses, send e-mail to: sales.addresses@www.semiconductors.philips.com.

Fax: +31 40 27 24825

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